

# SI2314EDS-T1-GE3

a Quote

### SI2314EDS-T1-GE3 Information

| Part Number  | SI2314EDS-T1-GE3  |   |
|--------------|---|---|
| Manufacturer | Vishay Siliconix  | in Nor  |
| Category     | Discrete Semiconductor Products<br>Transistors - FETs, MOSFETs - Single |   |
| Description  | MOSFET N-CH 20V 3.77A SOT23-3   |   |
| Package      | TO-236-3, SC-59, SOT-23-3   | ക്ഷ്  |
|              | For the pricing/inventory/lead time, please contact us                  | E1,434  |
|              | Website: https://www.heisener.com<br>E-mail: salesdept@heisener.com     | Request a   |
|              | Manufacturer<br>Category<br>Description                                 | ManufacturerVishay SiliconixCategoryDiscrete Semiconductor Products<br>Transistors - FETs, MOSFETs - SingleDescriptionMOSFET N-CH 20V 3.77A SOT23-3PackageTO-236-3, SC-59, SOT-23-3<br>For the pricing/inventory/lead time, please contact<br>us<br>Website: https://www.heisener.com |

### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## SI2314EDS-T1-GE3 Specifications

| Manufacturer Part Number               | SI2314EDS-T1-GE3                     |
|--|--------------------------------------|
| Manufacturer                           | Vishay Siliconix                     |
| Category                               | Discrete Semiconductor Products      |
|  | Transistors - FETs, MOSFETs - Single |
| Package                                | TO-236-3, SC-59, SOT-23-3            |
| Series                                 | TrenchFET?                           |
| FET Type                               | N-Channel                            |
| Technology                             | MOSFET (Metal Oxide)                 |
| Drain to Source Voltage (Vdss)         | 20V                                  |
| Current - Continuous Drain (Id) @ 25°C | 3.77A (Ta)                           |
| Drive Voltage (Max Rds On, Min Rds On) | 1.8V, 4.5V                           |
| Vgs(th) (Max) @ Id                     | 950mV @ 250µA                        |
| Gate Charge (Qg) (Max) @ Vgs           | 14nC @ 4.5V                          |
| Input Capacitance (Ciss) (Max) @ Vds   | -                                    |
| Vgs (Max)                              | ±12V                                 |
| FET Feature                            | -                                    |
| Power Dissipation (Max)                | 750mW (Ta)                           |
| Rds On (Max) @ Id, Vgs                 | 33 mOhm @ 5A, 4.5V                   |
| Operating Temperature                  | -55°C ~ 150°C (TJ)                   |
| Mounting Type                          | Surface Mount                        |
| Supplier Device Package                | SOT-23-3 (TO-236)                    |
| Package / Case                         | TO-236-3, SC-59, SOT-23-3            |
|  | Report errors?                       |

### SI2314EDS-T1-GE3 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### SI2314EDS-T1-GE3 Payment Methods





If you have any question about SI2314EDS-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com